

NPN SILICON RF POWER TRANSISTOR

DESCRIPTION:

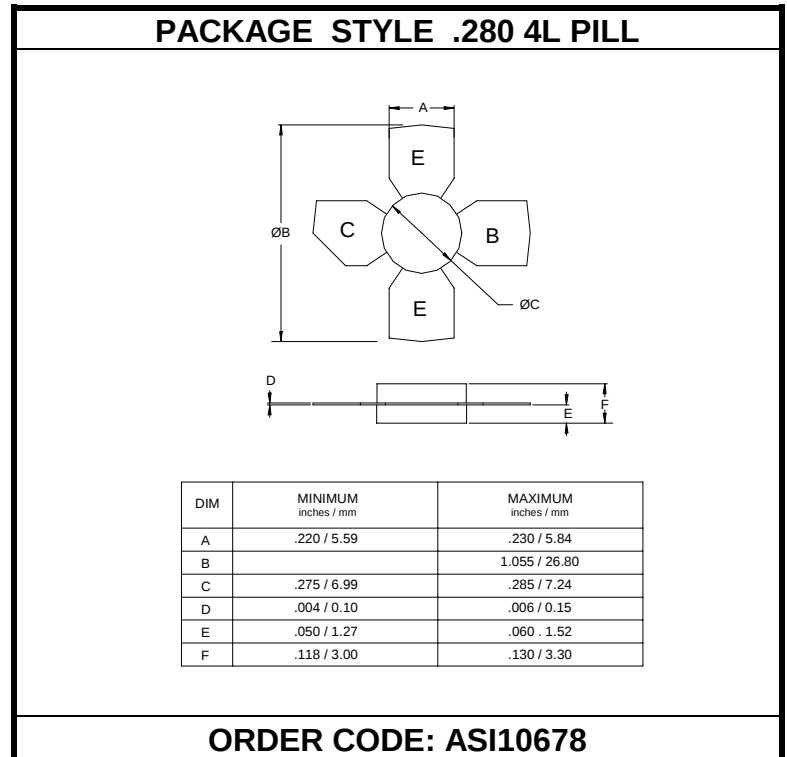
The **ASI ULBM2SL** is Designed for Class C, FM Land Mobile Applications up to 470 MHz.

FEATURES:

- Common Emitter
- $P_G = 10$ dB at 2.0 W/470 MHz
- **Omnigold™** Metalization System

MAXIMUM RATINGS

I_C	0.75 A
V_{CBO}	36 V
V_{CER}	16 V
V_{CES}	36 V
V_{EBO}	4.0 V
P_{DISS}	5.0 W @ $T_C = 25^\circ\text{C}$
T_J	-65°C to $+200^\circ\text{C}$
T_{STG}	-65°C to $+150^\circ\text{C}$
θ_{JC}	35.0 $^\circ\text{C/W}$



CHARACTERISTICS $T_C = 25^\circ\text{C}$

SYMBOL	TEST CONDITIONS		MINIMUM	TYPICAL	MAXIMUM	UNITS
BV_{CEO}	$I_C = 25$ mA		16			V
BV_{CES}	$I_C = 5.0$ mA		36			V
BV_{EBO}	$I_E = 1.0$ mA		4.0			V
I_{CBO}	$V_{CB} = 15$ V				1.0	mA
I_{CER}	$V_{CE} = 10$ V	$R_{BE} = 80 \Omega$			0.5	mA
h_{FE}	$V_{CE} = 5.0$ V	$I_C = 100$ mA	40		200	---
C_{ob}	$V_{CB} = 7.5$ V	$f = 1.0$ MHz			10	pF
P_G η_C	$V_{CC} = 12.5$ V	$P_{OUT} = 2.0$ W $f = 470$ MHz	10	60		dB %